

# Materials Availability for TW Scale Photovoltaics

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# Survey of audience

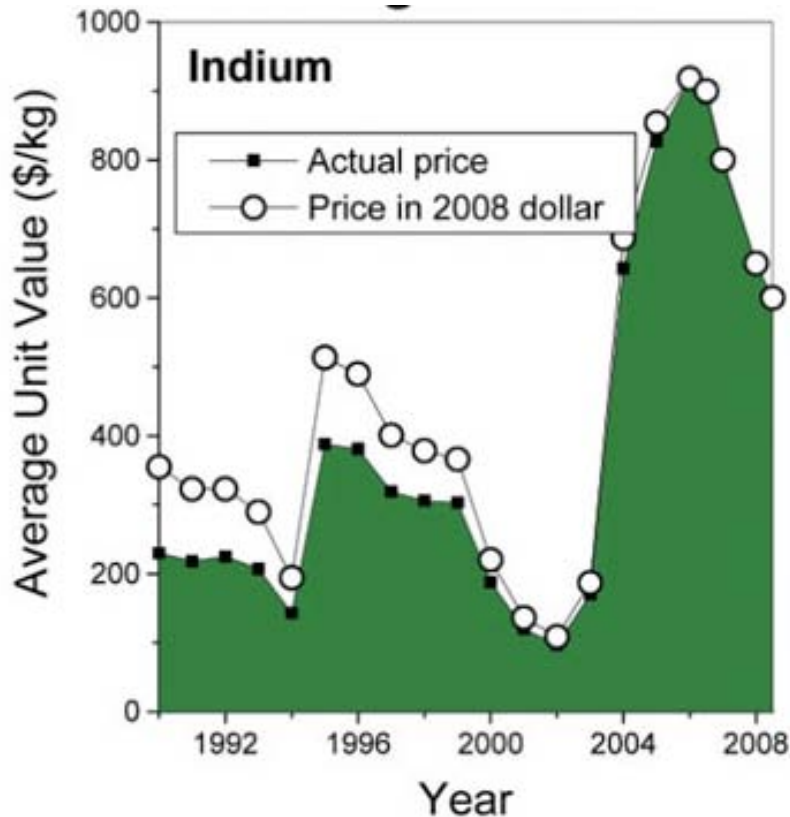
- a) Current thin film technologies, CdTe, CIGS & thin film Si will grow at rates that will accumulate to  $\sim 10$  TW by sometime between 2050-2100.
- a) Above statement can not be true. We will need other (new) materials and technologies other than or in addition to CdTe, CIGS & thin film Si to achieve  $\sim 10$  TW by sometime between 2050-2100.
- One can defend any one of these statements with seemingly reasonable assumptions.

# References addressing the materials availability issue

- Fthenakis “Sustainability of photovoltaics: the case for thin-film solar cells.” *Renewable and Sustainable Energy Reviews* **23**, 2746 (2009).
- Wadia, Alivisatos & Kammen, “Materials availability expands the opportunity for large scale photovoltaics development.” *Environ. Sci. Technol.* **43**, 2072 (2009).
- Zweibel, “The Terrawatt challenge for thin film PV: A work in progress” NREL Report (2006).
- Andersson, “Materials availability for large-scale thin-film photovoltaics,” *Prog. Photovoltaics* **8**, 61 (2000).



# Another limitation could be the price

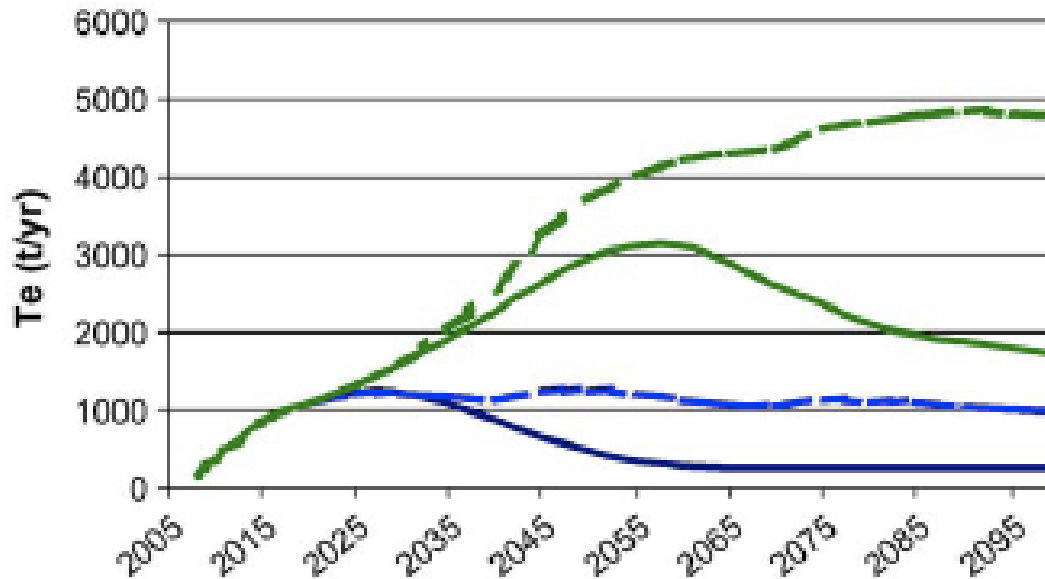


September 2008 - "SMG filed an IPO to raise \$55 million on the American Stock Exchange – plans to use the money it raises to stockpile indium in the hope of selling it for higher prices in the future."

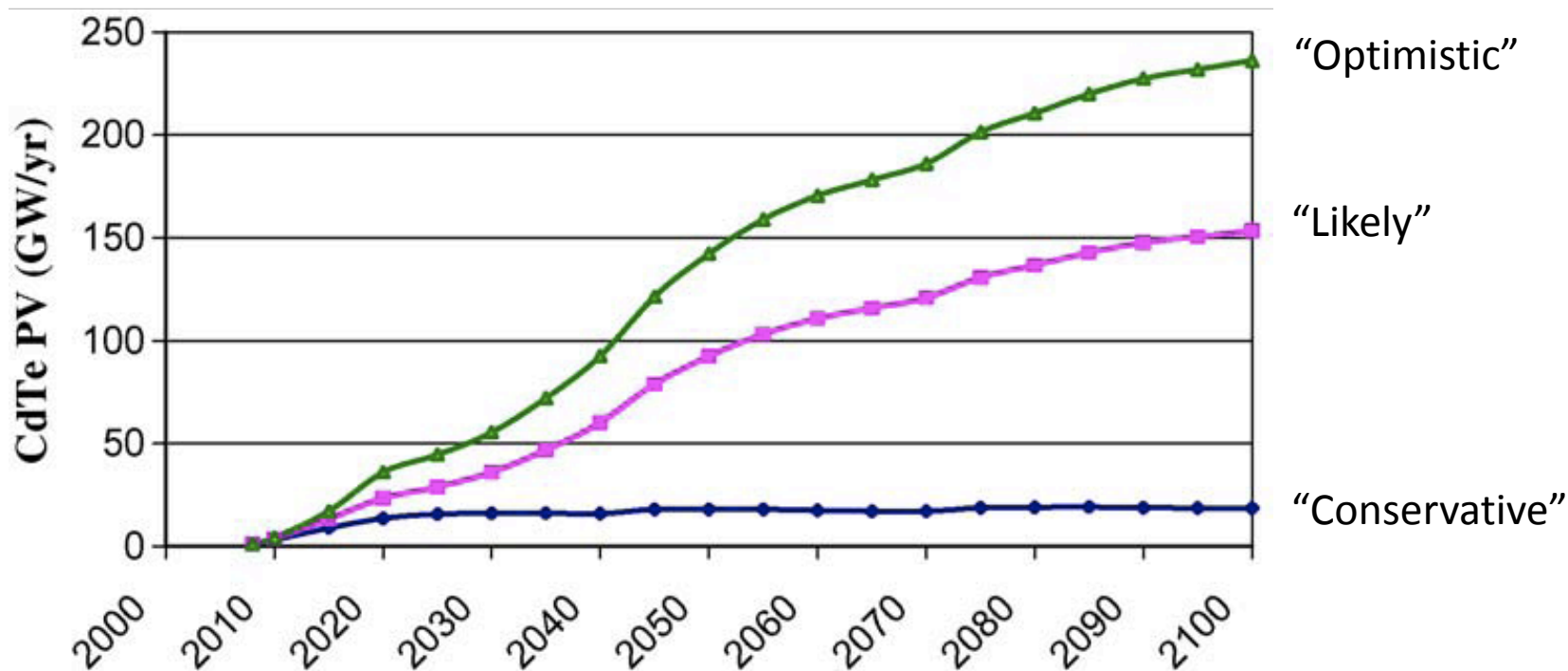
- If rare others may want it too.
- Supply & demand difficult to predict

# Te availability may limit the growth rate of CdTe PV

- Te is a byproduct of Cu production
- Te production rate tied to Cu production
- ~ 30-40% of available Te is recovered
- Cu production is uncertain

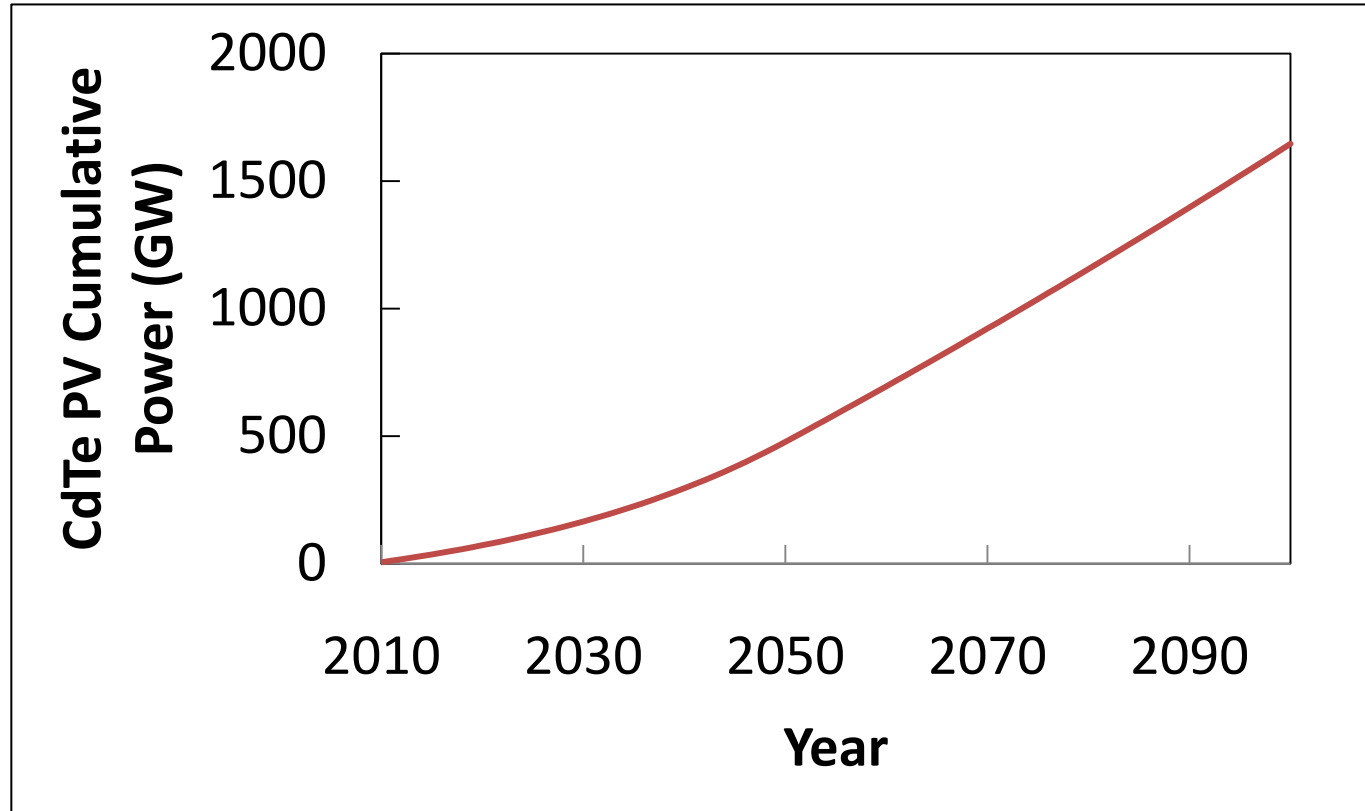


# Projected growth rate limits for CdTe solar cells based on Te Availability



- Cu production peaks 2025 or 2060
- ~ 80% of available Te is recovered
- CdTe thickness down to 1  $\mu\text{m}$ , efficiency up to 14%
- All scenarios include secondary recovery

# Projected growth rate limits for CdTe solar cells based on Te Availability

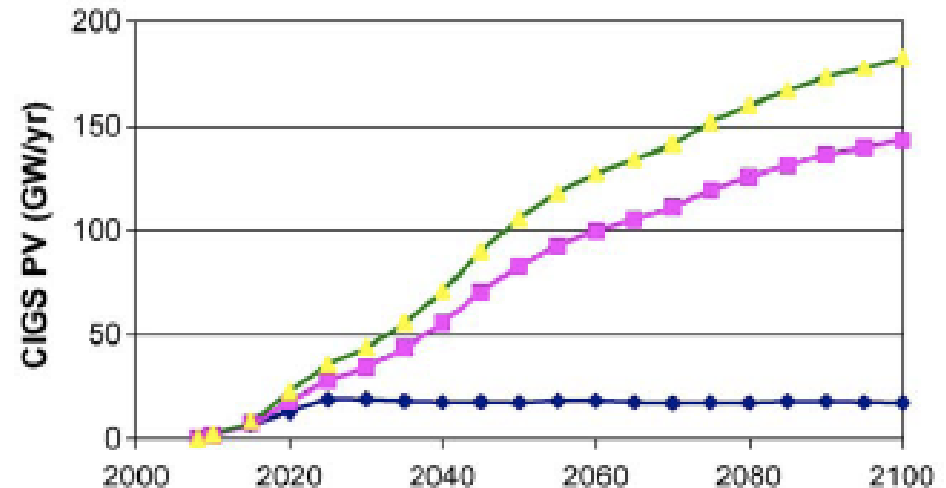
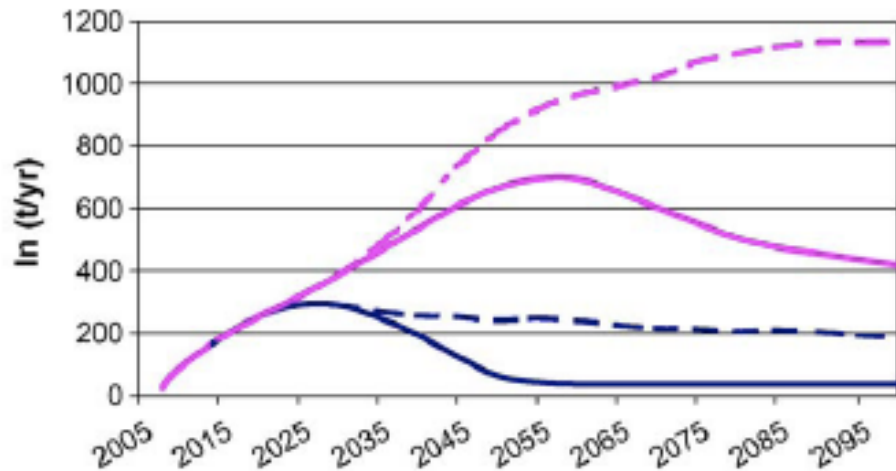


- Cu production grows to 2060 and remains constant at 53 Mt/year
- ~ 33% of available Te is recovered
- CdTe thickness 2  $\mu\text{m}$ , efficiency up to 15 %

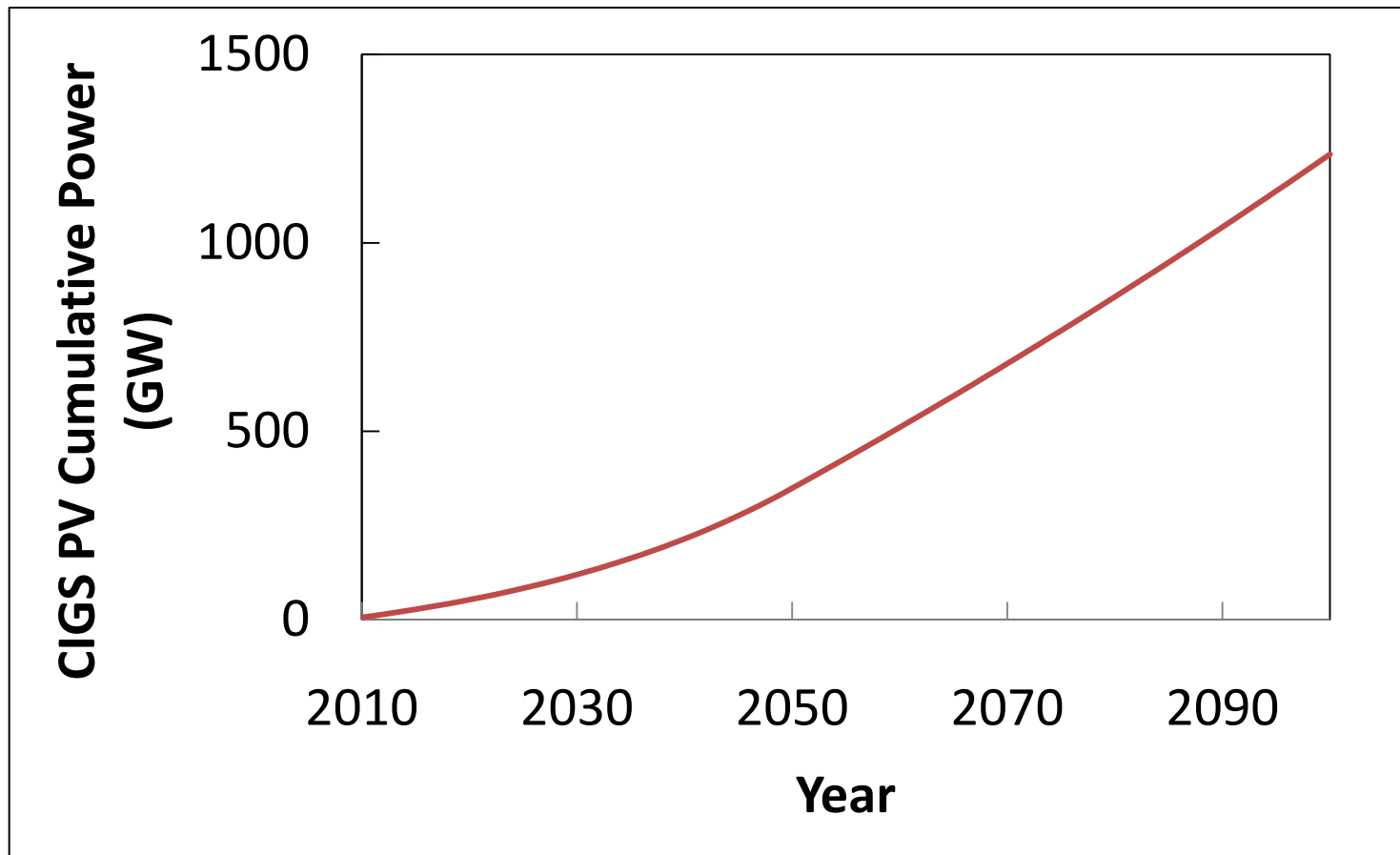


# In availability may limit the growth rate of CIGS PV

- In is a byproduct of Zn production
- Te production rate tied to Zn production
- ~ 70-80 % of available In is recovered

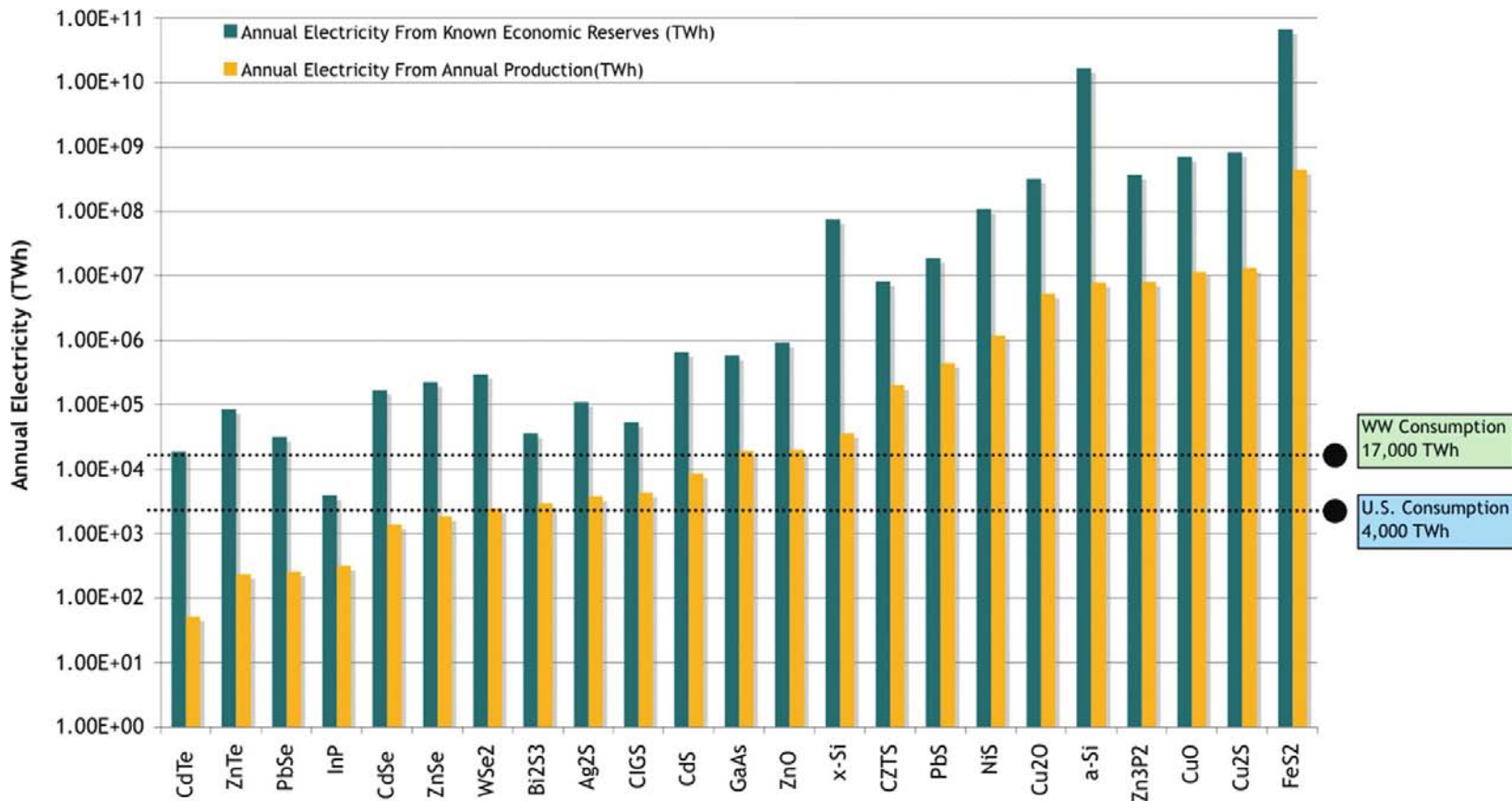


# Projected growth rate limits for CIGS solar cells based on In Availability

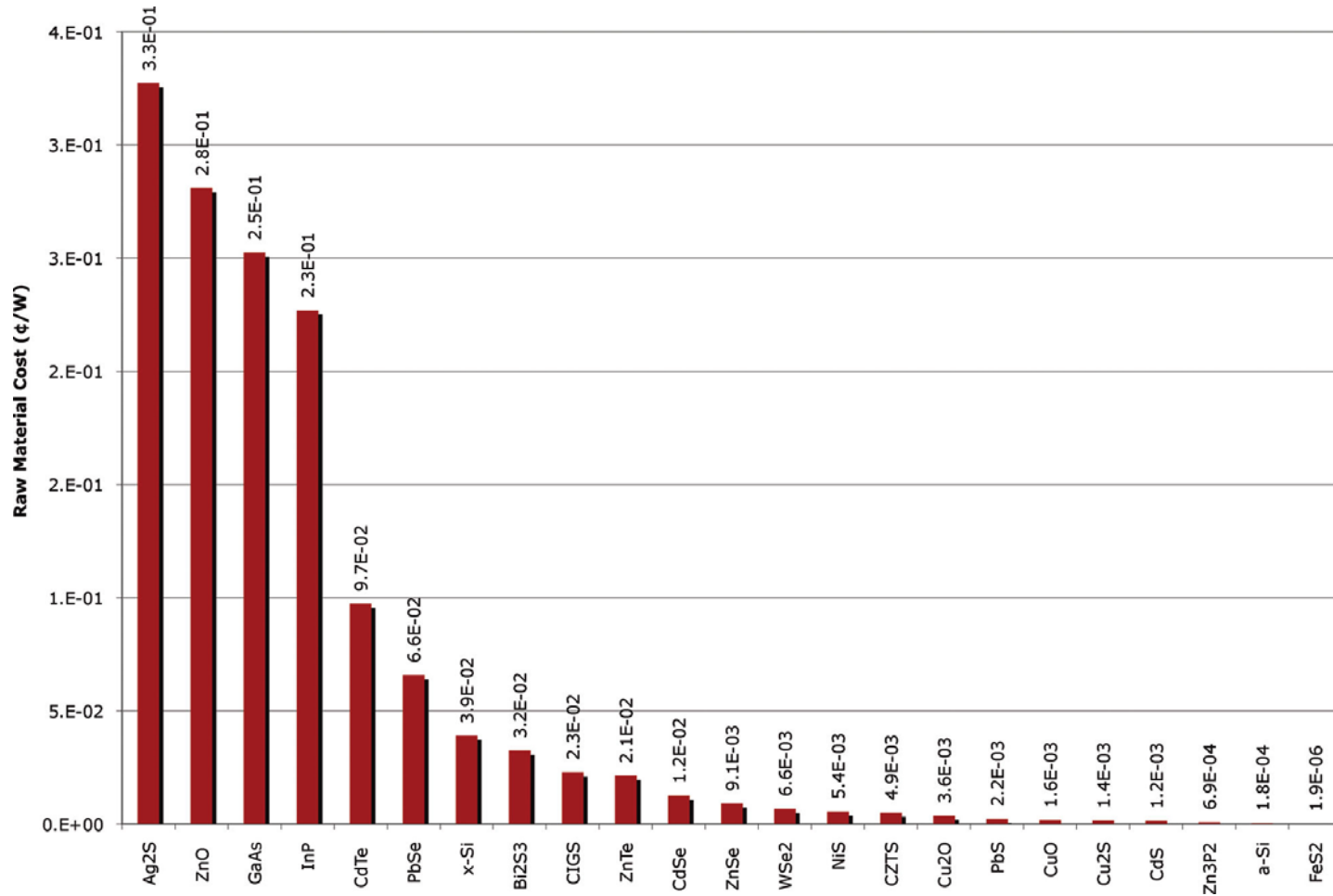


- Zn production grows to 2060 and remains constant at 11 Mt/year
- ~ 80% of available In is recovered
- CdTe thickness 1.6  $\mu\text{m}$ , efficiency up to 17 %

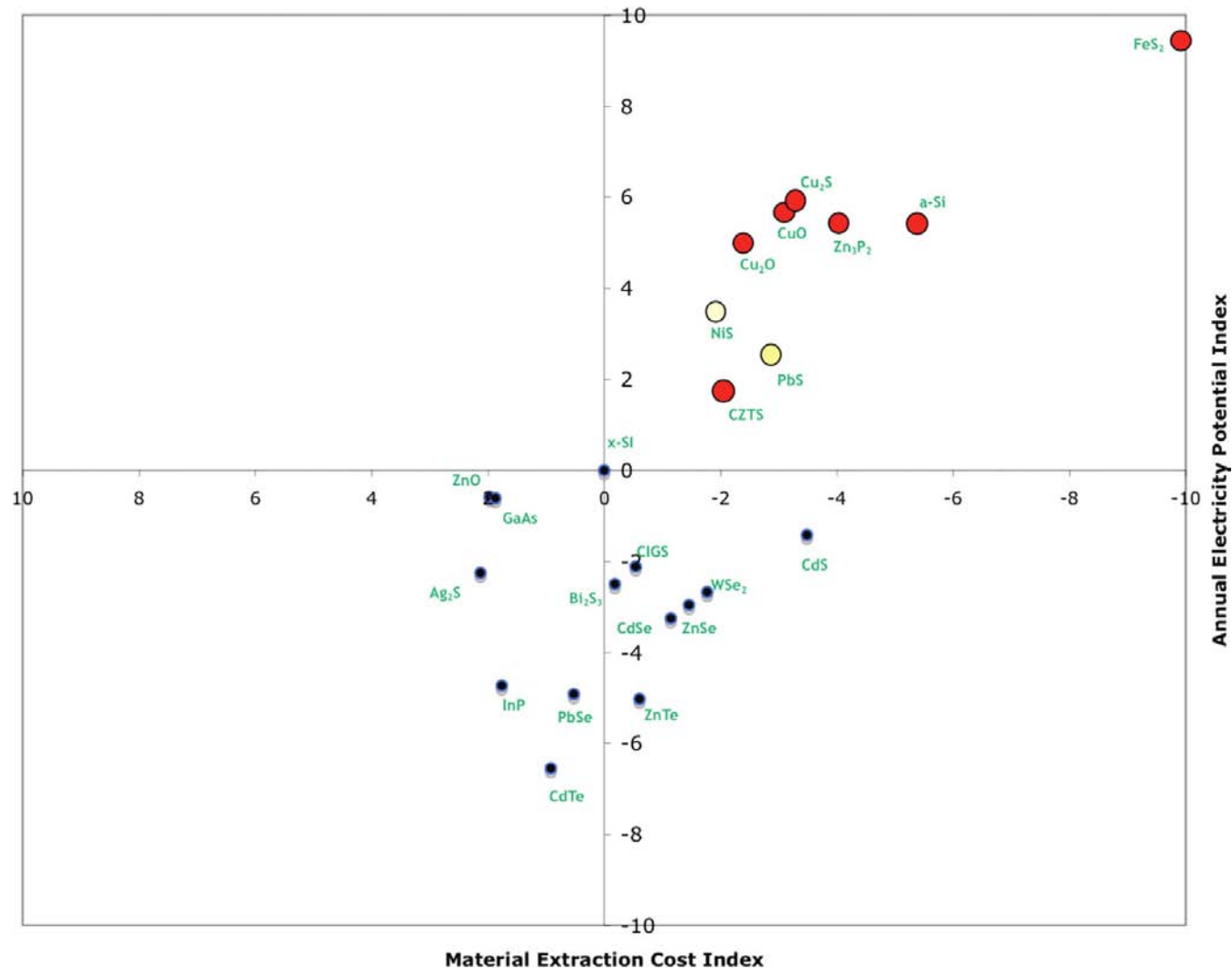
# Annual electricity production potential of common inorganic semiconductors



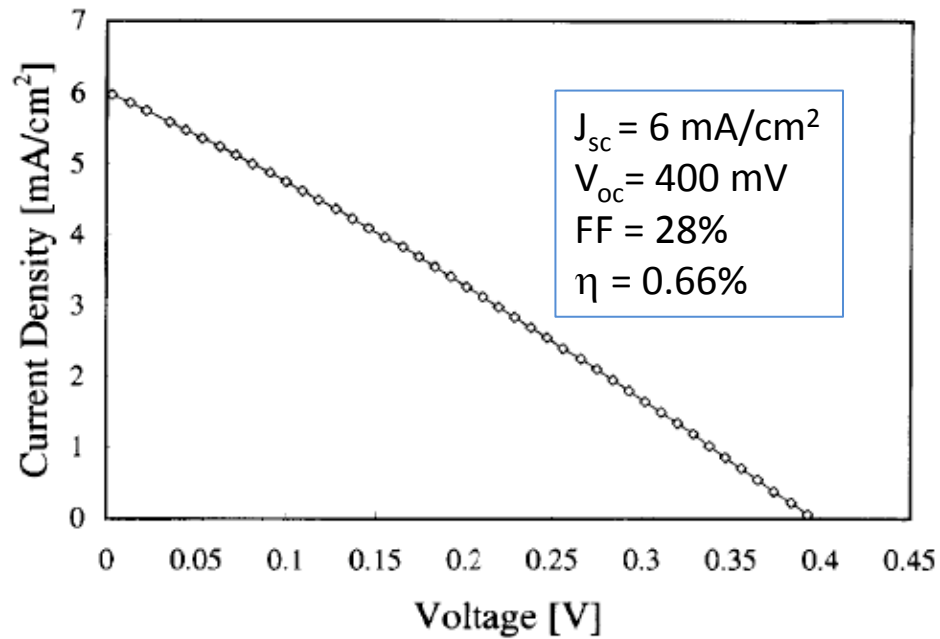
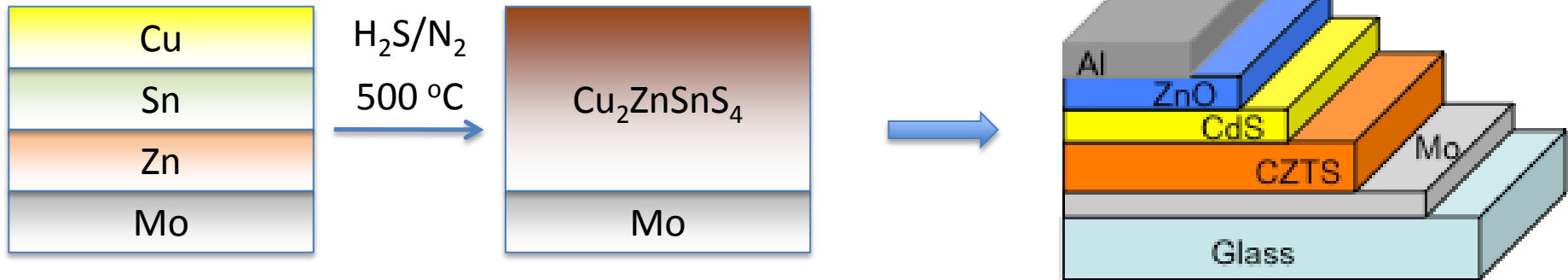
# Raw materials cost of common inorganic semiconductors



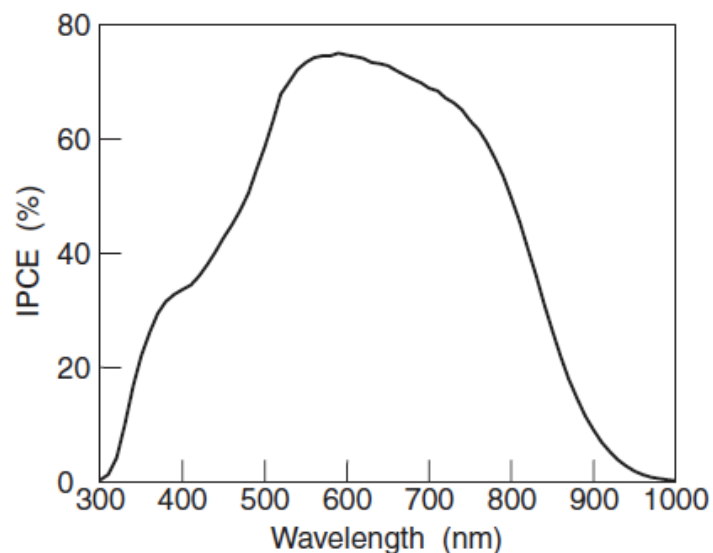
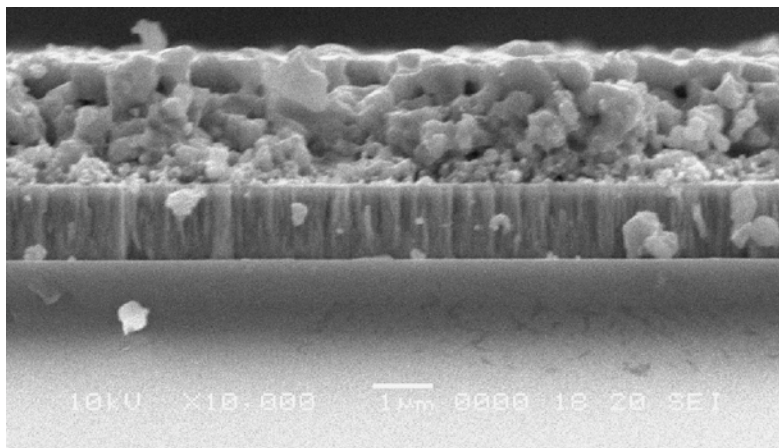
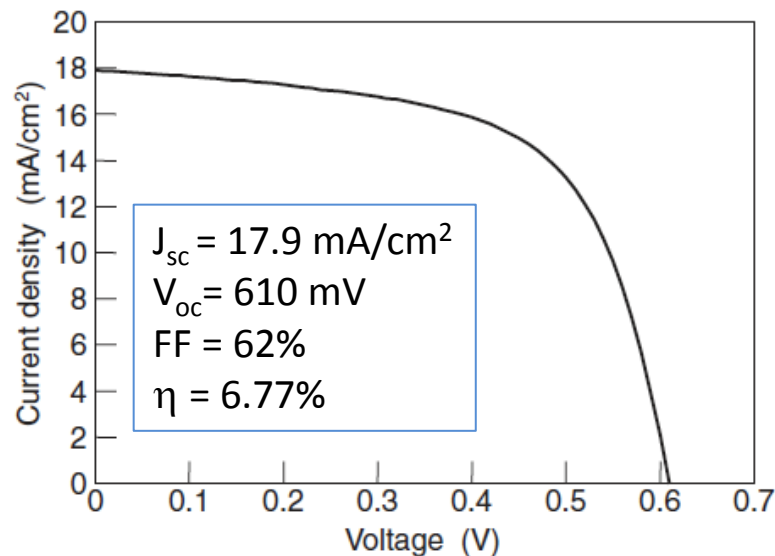
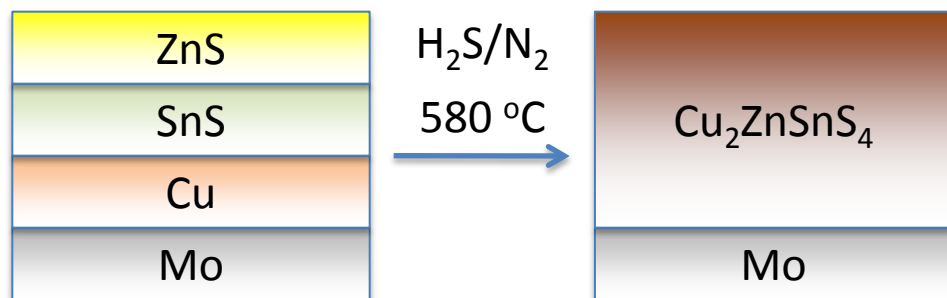
Which materials have extraction costs lower than Si and electricity producing potential greater than Si?



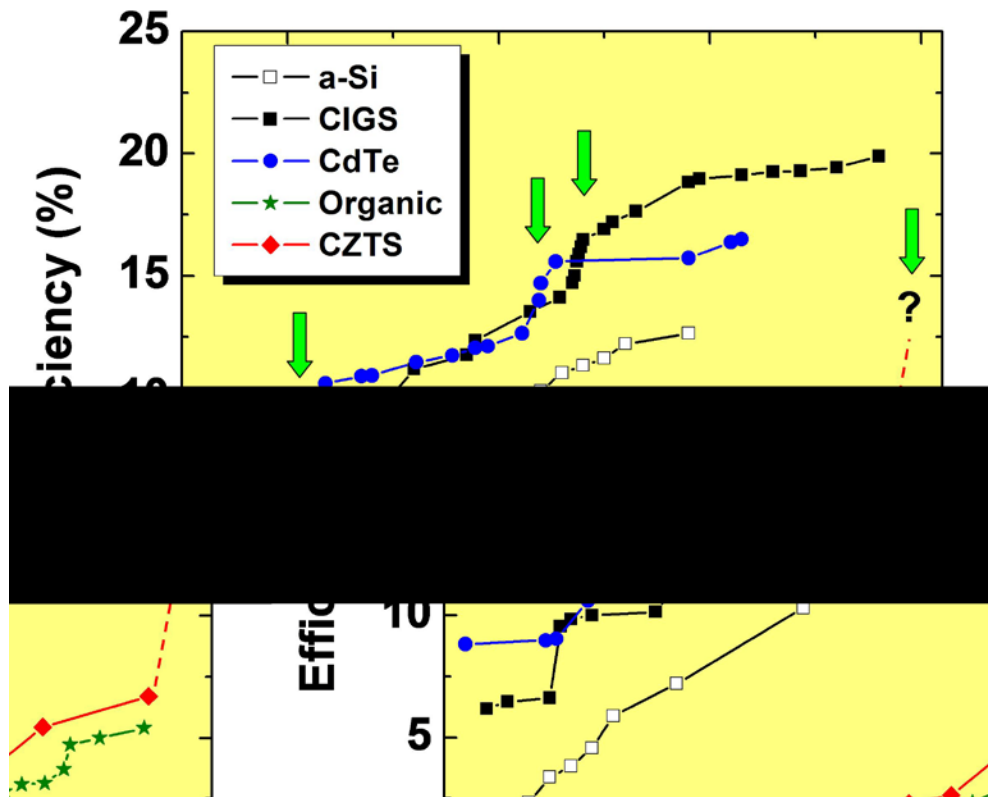
# CZTS Solar Cells by Sulfurization of a stack of evaporated Zn/Sn/Cu films



# CZTS Solar Cells by Sulfurization of co-sputtered Cu, SnS and ZnS film



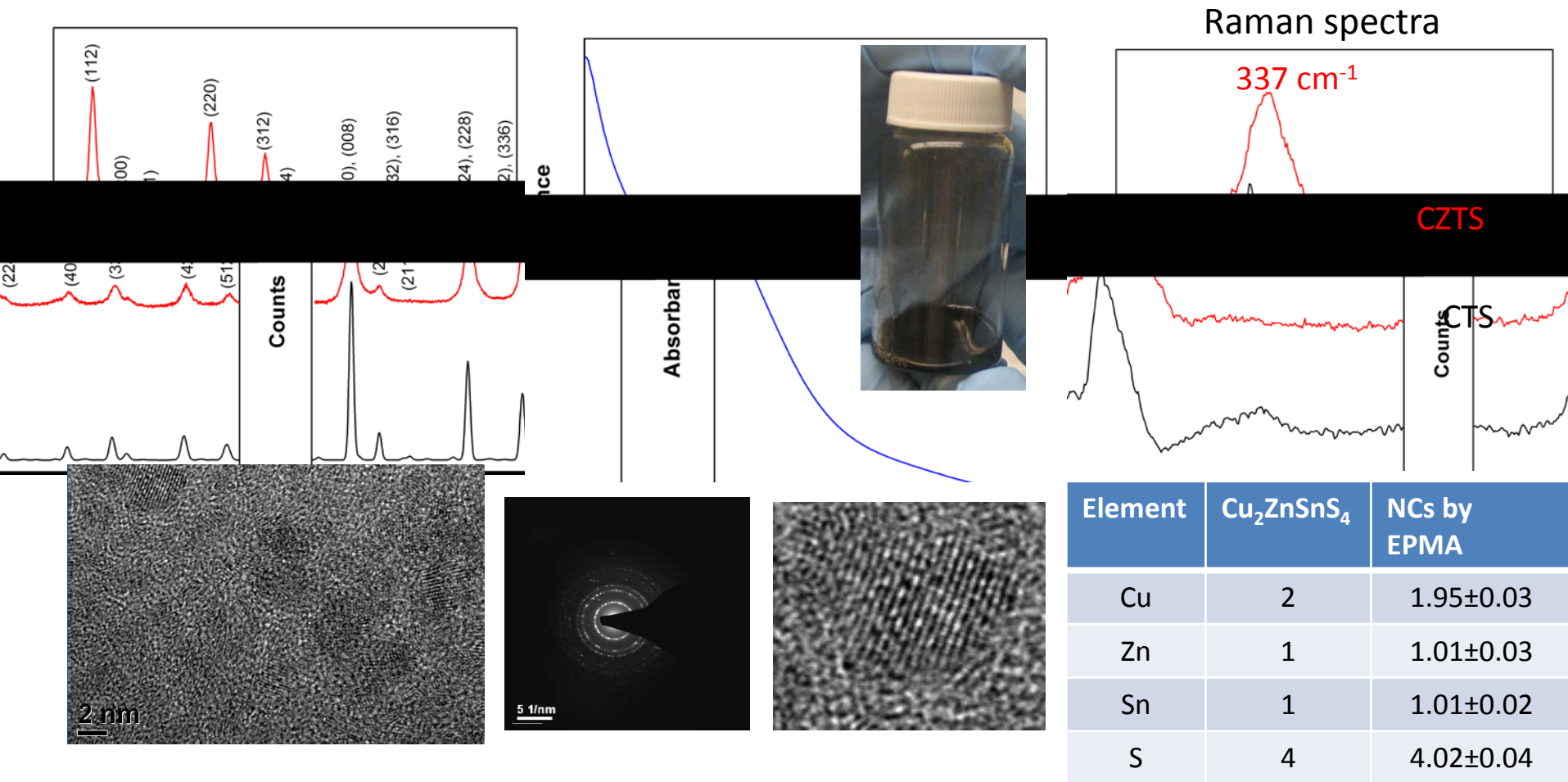
# Evolution of CZTS power conversion efficiency



- ~ 600 articles keywords = CIGS and solar
- ~ 1300 articles keywords = CdTe and solar
- ~ 6800 articles keywords = organic and solar
- ~ 7100 articles keywords = a-Si and solar
- ~ 50 articles keywords = CZTS and solar

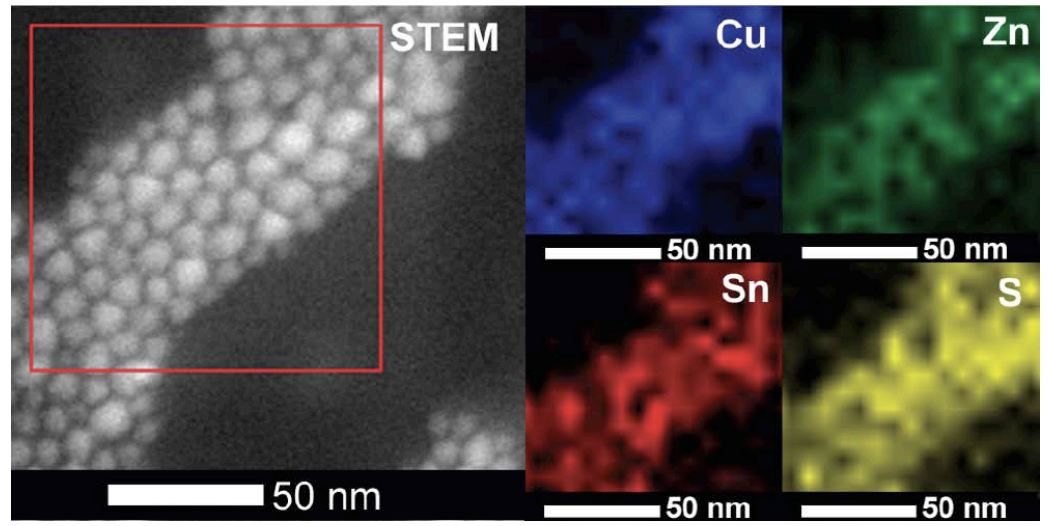
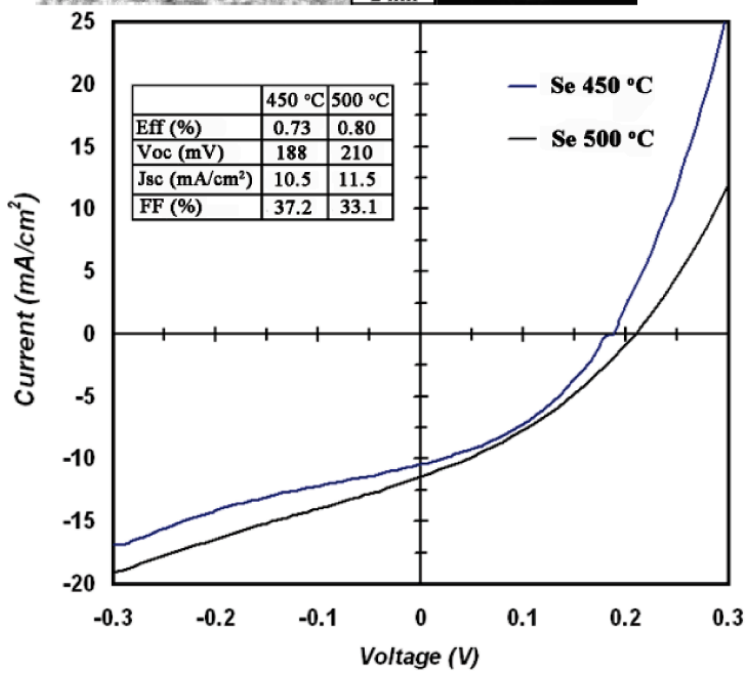
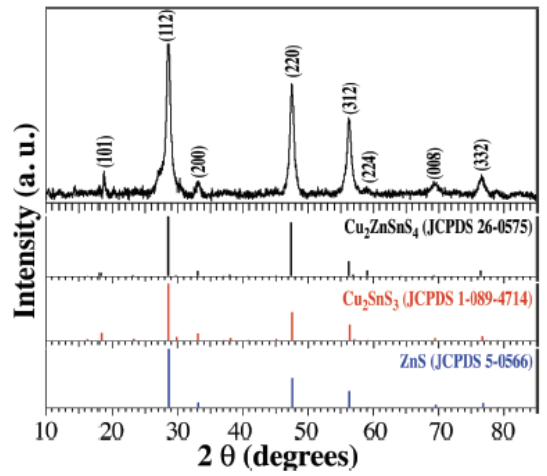
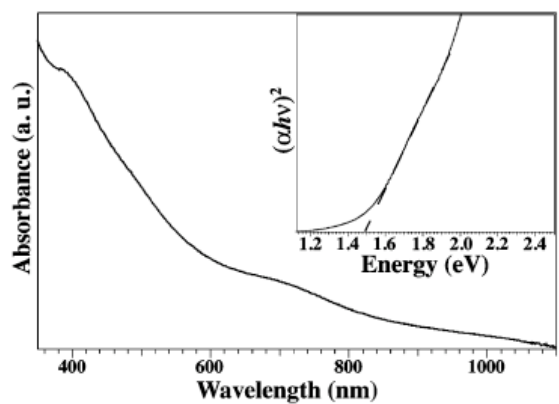
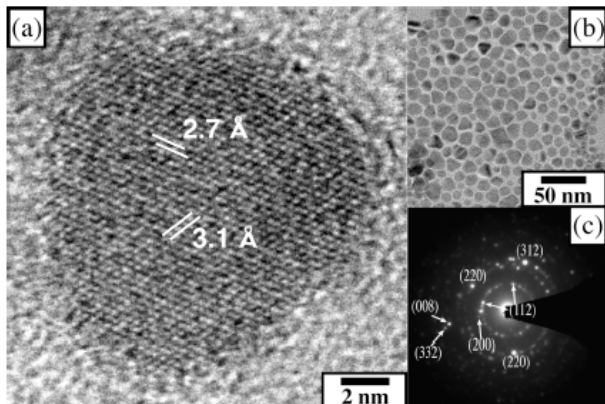


# Cu<sub>2</sub>ZnSnS<sub>4</sub> (CZTS)



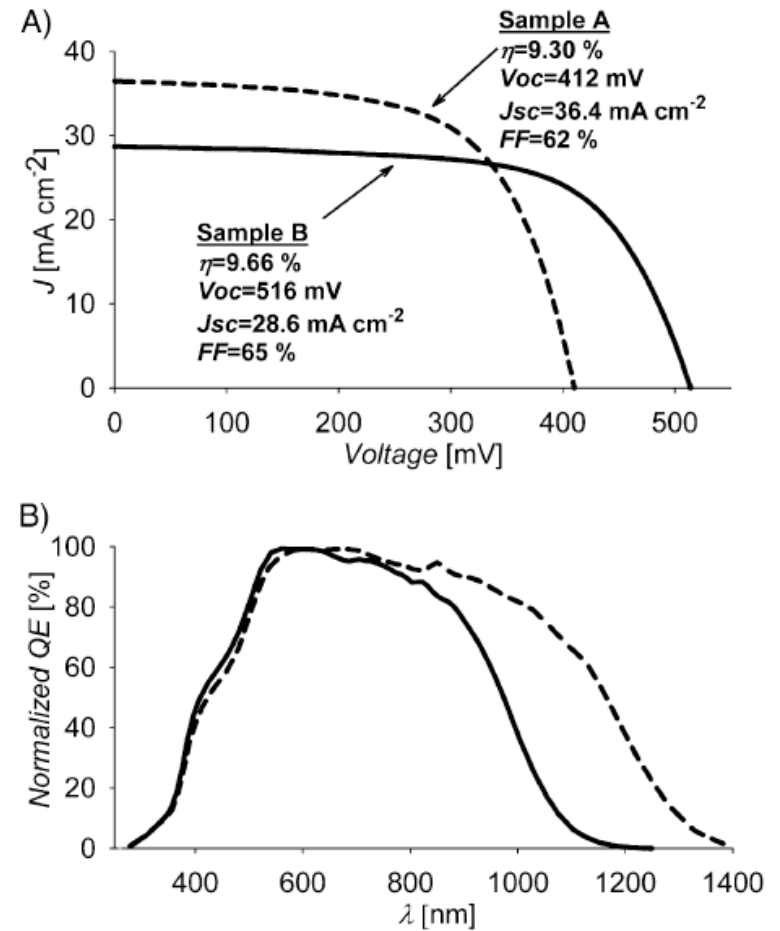
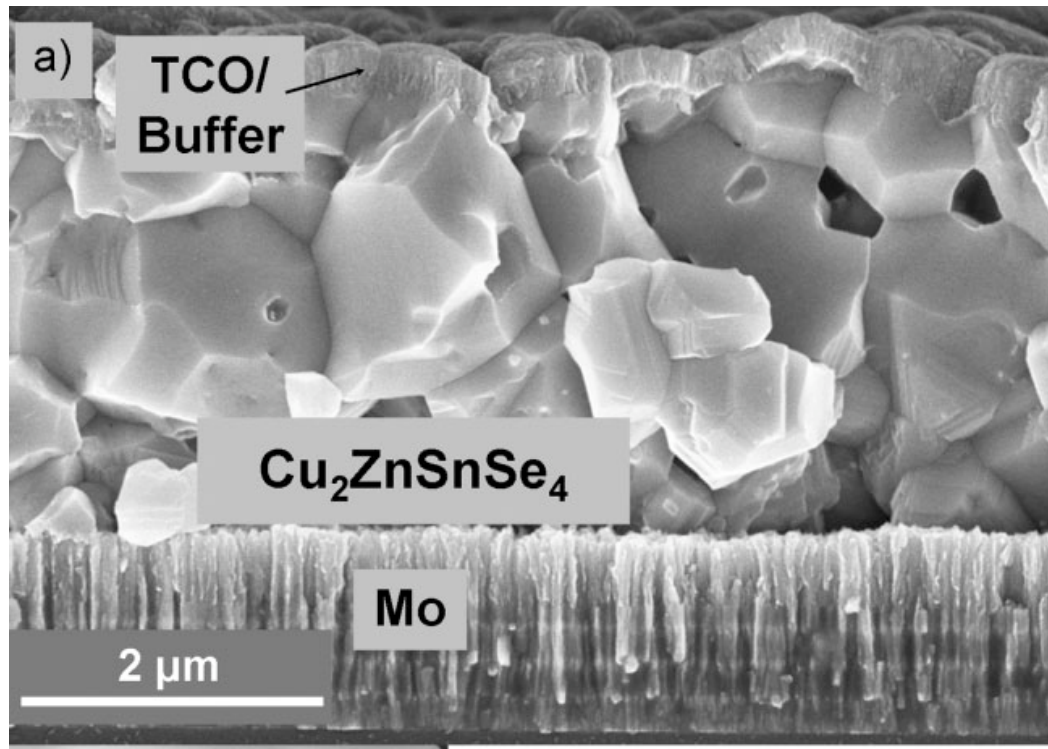
- Synthesized 2-10 nm CZTS nanocrystals from metal dithiocarbamates
- Stable colloidal dispersions in organic solvents
- HRTEM, XRD, Raman, EPMA, optical absorption consistent with CZTS

# Solar cells with films cast from CZTS colloidal nanocrystal solutions

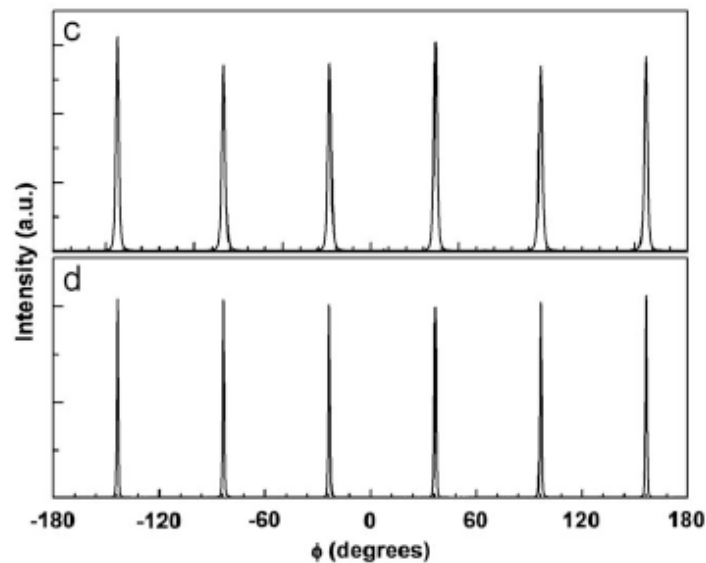
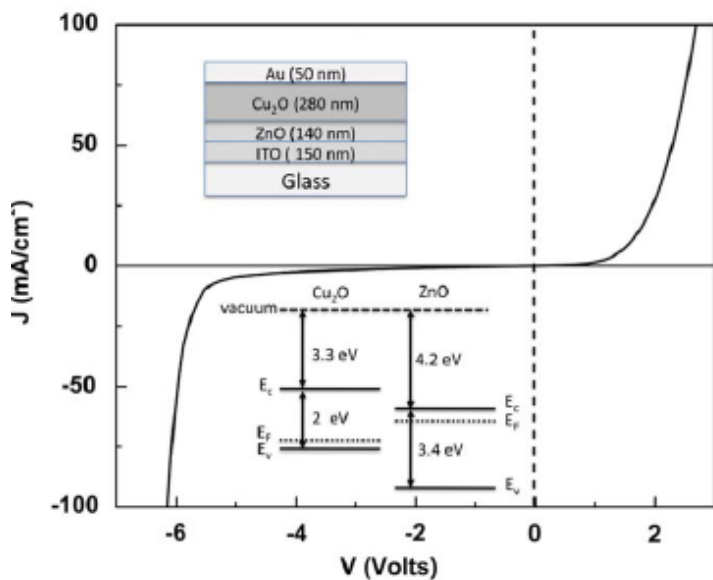
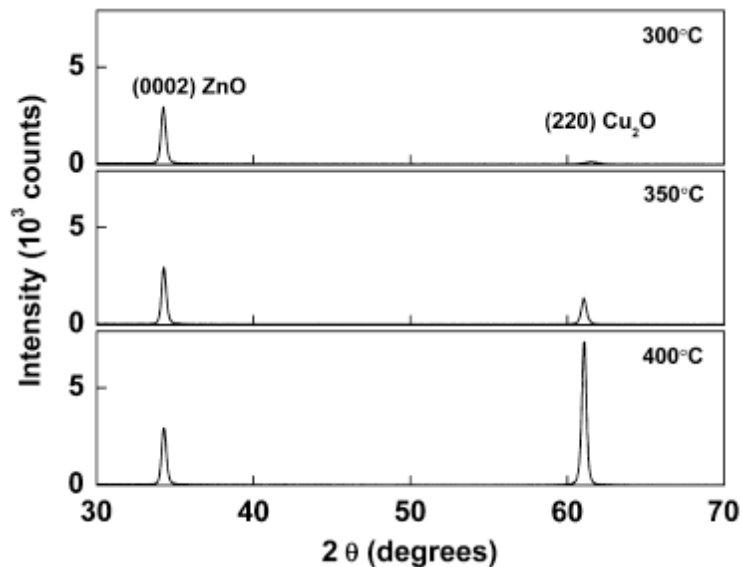
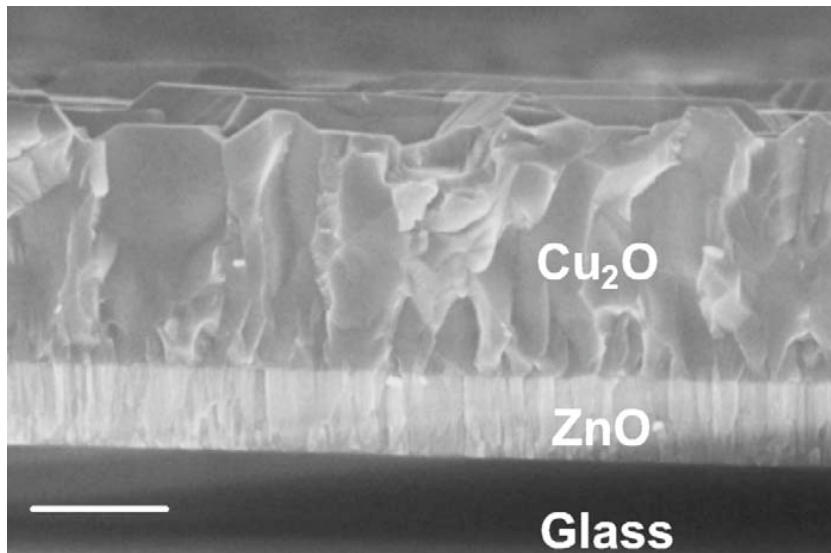


Riha, Parkinson & Prieto, JACS **131**, 1 (2009); Guo, Hillhouse & Agrawal, JACS **131**, 11672 (2009); Steinhagen, Panthani, Akhavan, Goodfellow, Koo & Korgel, JACS **131**, 12554 (2009);

# High-Efficiency Solar Cell with Earth-Abundant Liquid-Processed Absorber

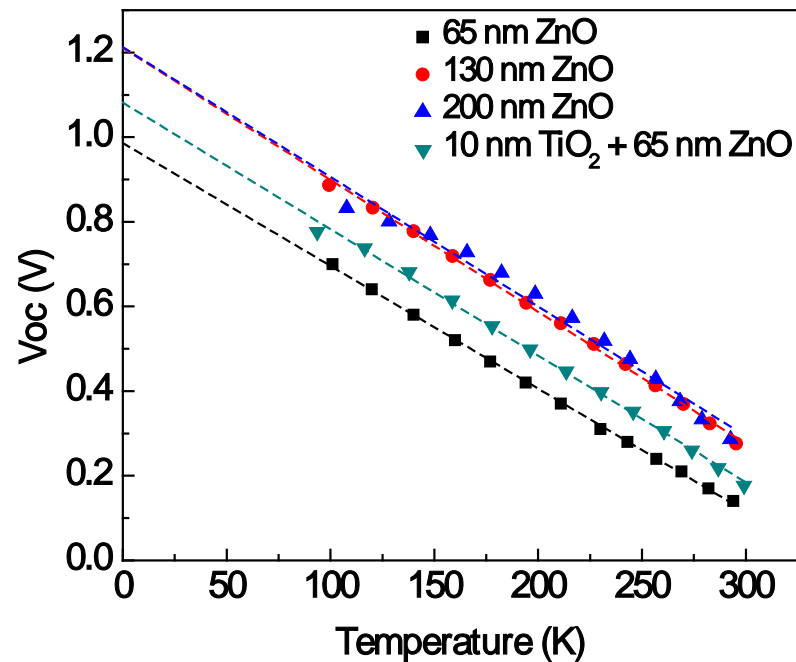


# Cu<sub>2</sub>O-ZnO heterojunction solar cells



# Cu<sub>2</sub>O-ZnO heterojunction solar cells

- efficiencies (~1-2%) and  $V_{oc}$  (~0.1-0.4 V) so far has been low
- Interface quality and defects implicated for poor performance



# Summary

- a) Current thin film technologies, CdTe, CIGS & thin film Si **may** grow at rates that will accumulate to ~10 TW by sometime between 2050-2100.
  
- a) We will need other (new) materials and technologies in addition to CdTe, CIGS & thin film Si to achieve ~10 TW by sometime between 2050-2100.